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TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSⅢ)

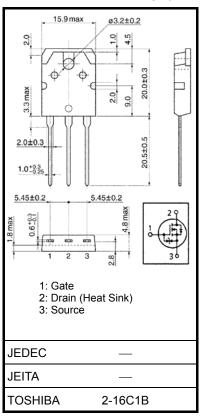
TK70J04J3

Motor Drive Application

- Low drain-source ON resistance: R_{DS (ON)} = 3.0 mΩ (typ.)
- High forward transfer admittance: |Y_{fs}| = 120 S (typ.)
- Low leakage current: I_{DSS} = 10 μA (max) (V_{DS} = 40 V)
- Enhancement mode: V_{th} = 1.5 to 3.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Character	Symbol	Rating	Unit	
Drain-source voltage	V _{DSS}	40	V	
Drain-gate voltage (R	V _{DGR}	40	V	
Gate-source voltage	V _{GSS}	±20	V	
Drain current	DC (Note 1)	ID	70	А
	Pulse (Note 1)	I _{DP}	280	А
Drain power dissipatio	n (Tc = 25°C)	PD	150	W
Single pulse avalanche	e energy (Note 2)	E _{AS}	528	mJ
Avalanche current	I _{AR}	70	А	
Repetitive avalanche e	E _{AR}	15	mJ	
Channel temperature	T _{ch}	175	°C	
Storage temperature r	T _{stg}	-55~175	°C	



Weight : 4.6 g (typ.)

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch−c)}	1.0	°C / W
Thermal resistance, channel to ambient	R _{th (ch−a)}	50	°C / W

Note 1: Please use devices on condition that the channel temperature is below 175°C.

Note 2: V_DD = 25 V, T_ch = 25°C (initial), L = 112 μ H, R_G = 25 Ω , I_{AR} = 70A

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

Note 4: The definition of maximum rating condition for both channel temperature and storage temperature range are referred from AEC-Q101.

Note 5: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic sensitive device. Please handle with caution. Unit: mm

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Electrical Characteristics (Ta = 25°C)

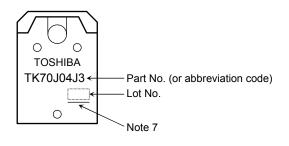
Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V_{GS} = ±16 V, V_{DS} = 0 V	_	—	±10	μA
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V		_	10	μA
Drain-source breakdown voltage		V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	40	—	_	V
		V _(BR) DSX	I _D = 10 mA, V _{GS} = -20 V	15 —		_	v
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	1.5	_	3.0	V
Drain-source ON resistance (Note 6)		ſ	V _{GS} = 4.5 V, I _D = 35 A		4.6	8.3	mΩ
		R _{DS} (ON)	V _{GS} = 10V, I _D = 35A		3.0	3.8	
Forward transfe	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 35 A	60	120	_	S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	12400	_	pF
Reverse transfer capacitance		C _{rss}			850	—	
Output capacitance		C _{oss}			1350	_	
Switching time	Rise time	tr	$V_{GS} \stackrel{10}{}_{0}V \qquad I_{D} = 35 \text{ A}$	—	12	_	- ns
	Turn-on time	t _{on}			40	_	
	Fall time	t _f		_	65	_	
	Turn-off time	t _{off}	$V_{DD}\simeq 20~V \label{eq:VDD}$ Duty \leq 1%, $t_W=$ 10 μs	_	260 —		
Total gate charge (Gate-source plus gate-drain)		Qg	V _{DD} ≈ 32 V, V _{GS} = 10 V, I _D = 70 A	_	210	_	nC
Gate source charge		Q _{gs}		_	150	_	
Gate-drain ("miller") charge		Q _{gd}]		60	—	

Note 6: Measured at lead standoff.

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	70	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	280	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 70 A, V _{GS} = 0 V	_	_	-1.5	V
Reverse recovery time	t _{rr}	I _{DR} = 70 A, V _{GS} = 0 V		65	—	ns
Reverse recovered charge	Q _{rr}	dI _{DR} / dt = 50 A / μs	_	55	_	nC

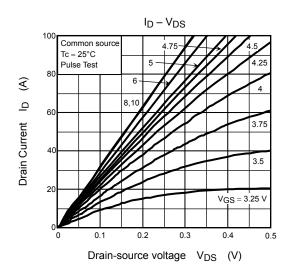
Marking

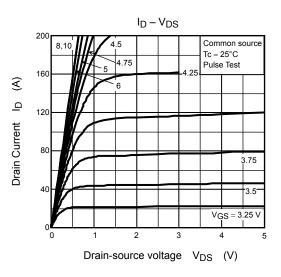


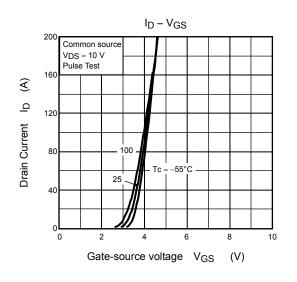
Note 7: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

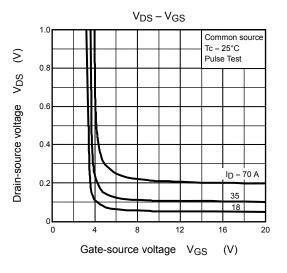
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

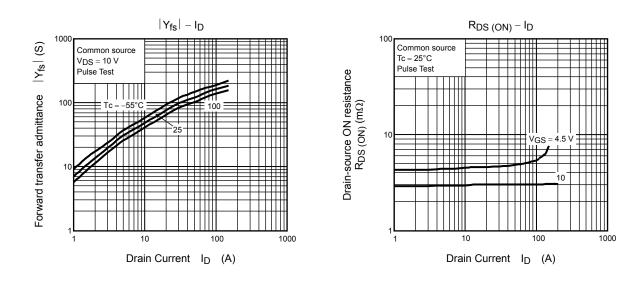
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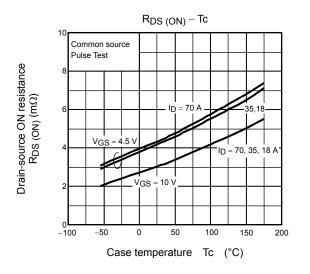


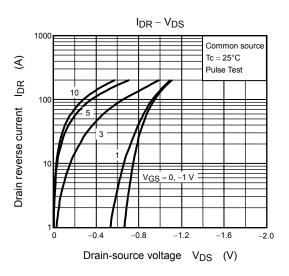


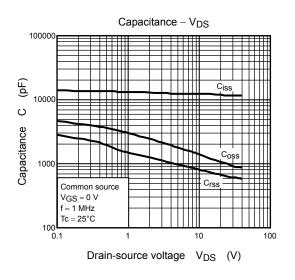


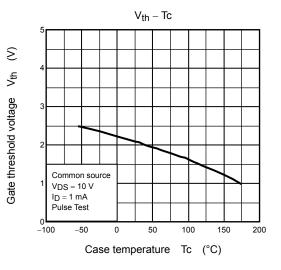
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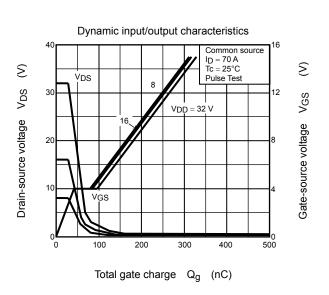
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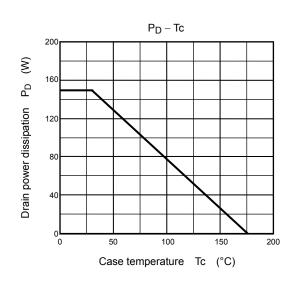


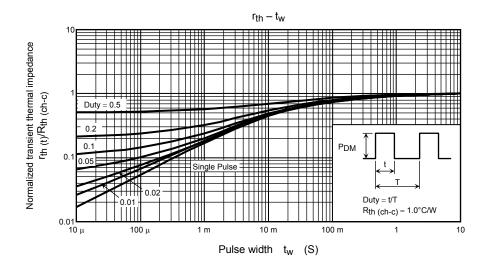




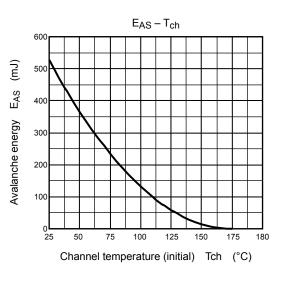


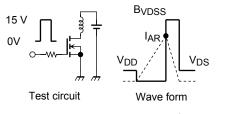






Safe operating area 1000 ID m (Pulse) 100 μs 100 ID n tinuous E Drain Current I_D DC operation Tc = 25°C 10 : Single nonrepetitive pulse Tc = 25°C Curves must be derated linearly with increase in temperature. 0.1**L** 0.1 VDSS ma 10 1 100 Drain-source voltage V_{DS} (V)





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